

PIN Silicon Photodiode

OP993, OP999



Features:

- Choice of TO-18 (OP993) or T-1¾ package (OP999)
- Small package style ideal for space-limited applications
- Linear response vs. irradiance
- Fast switching time
- Choice of narrow or wide receiving angle

Description:

Each **OP993** and **OP999** device consists of a PIN silicon photodiode molded in a dark blue injection molded shell package that provides excellent optical and mechanical axis alignment, optical lens surface, control of chip placement and consistency of the outside package dimensions.

OP993 has a TO-18 package style and a *wide* receiving angle that provides excellent on-axis coupling. **OP999** has a T-1¾ package style and a *narrow* receiving angle that provides excellent on-axis coupling.

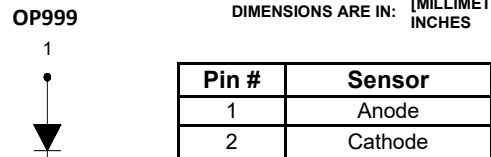
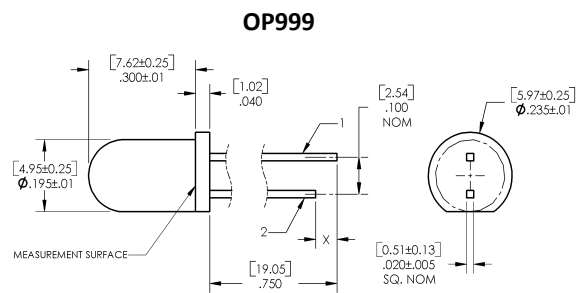
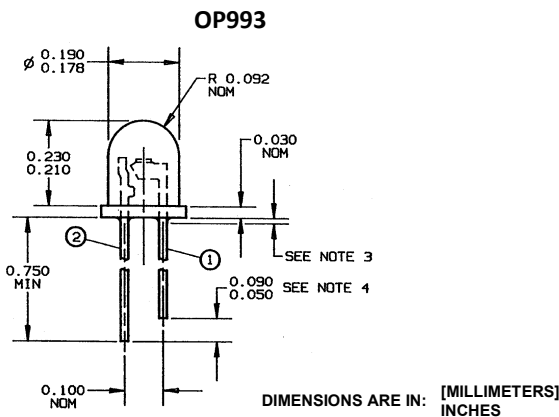
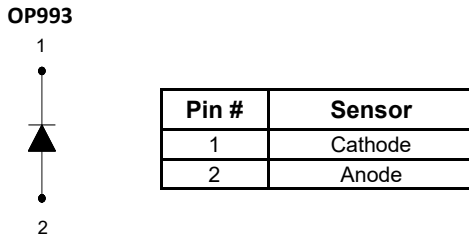
Both devices are 100% production tested for close correlation with OPTEK GaAIAs emitters.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Applications:

- Non-contact reflective object sensor
- Machine safety
- Assembly line automation
- End of travel sensor
- Machine automation
- Door sensor

Ordering Information			
Part Number	Sensor	Viewing Angle	Lead Length
OP993	Photodiode	118°	0.75 min
OP999	Photodiode	18°	



CONTAINS POLYSULFONE
 To avoid stress cracking, we suggest using ND Industries' **Vibra-Tite** for thread-locking. **Vibra-Tite** evaporates fast without causing structural failure in OPTEK'S molded plastics.



General Note
 TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

Electrical Specifications

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)	
Reverse Breakdown Voltage	60 V
Storage & Operating Temperature Range	-40°C to $+100^\circ\text{C}$
Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 sec. with soldering iron]	$260^\circ\text{C}^{(1)}$
Reverse Breakdown Voltage	60 V
Power Dissipation	$100\text{ mW}^{(2)}$

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)						
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
I_L	Reverse Light Current					
	OP993	12.5	-	28.5	μA	$V_R = 5\text{ V}, E_E = 1.7\text{ mW/cm}^2^{(3)}$
	OP999	6.5	-	15		$V_R = 5\text{ V}, E_E = 0.25\text{ mW/cm}^2^{(3)}$
I_D	Reverse Dark Current		1	60	nA	$V_R = 30\text{ V}, E_E = 0^{(4)}$
$V_{(BR)}$	Reverse Breakdown Voltage	60			V	$I_R = 100\ \mu\text{A}$
V_F	Forward Voltage			1.2	V	$I_F = 1\text{ mA}$
C_T	Total Capacitance		4		pF	$V_R = 20\text{ V}, E_E = 0, f = 1.0\text{ MHz}$
t_r	Rise Time		5		ns	$V_R = 20\text{ V}, \lambda = 850\text{ nm}, R_L = 50\ \Omega$
t_f	Fall Time		5			

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to leads when soldering.
- (2) Derate linearly $1.67\text{ mW}/^\circ\text{C}$ above 25°C .
- (3) Light source is an unfiltered GaAlAs emitting diode operating at peak emission wavelength of 890 nm and $E_{E(APT)}$ of 1.7 mW/cm^2 for OP993 and 0.25 mW/cm^2 for OP999 average within a 0.25" diameter aperture.
- (4) This dimension is held to within $\pm 0.005''$ on the flange edge and may vary up to $\pm 0.020''$ in the area of the leads.

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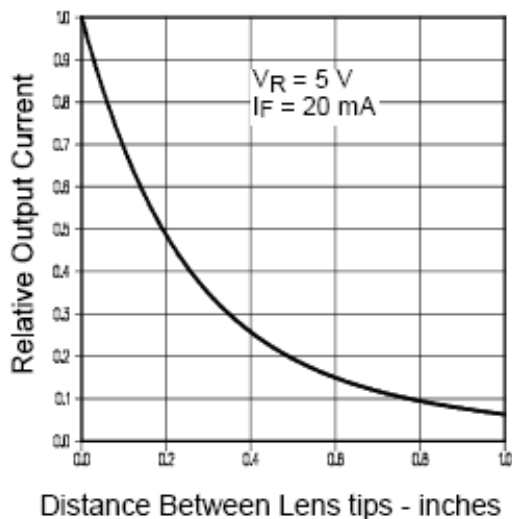
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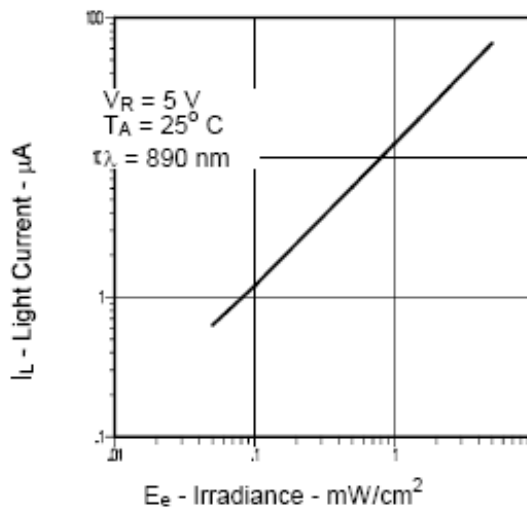


OP993

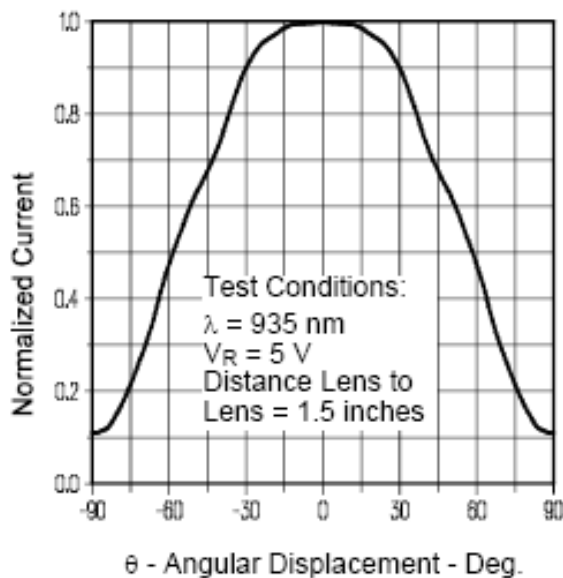
Coupling Characteristics OP993 and OP293



Light Current vs. Irradiance



Light Current vs. Angular Displacement



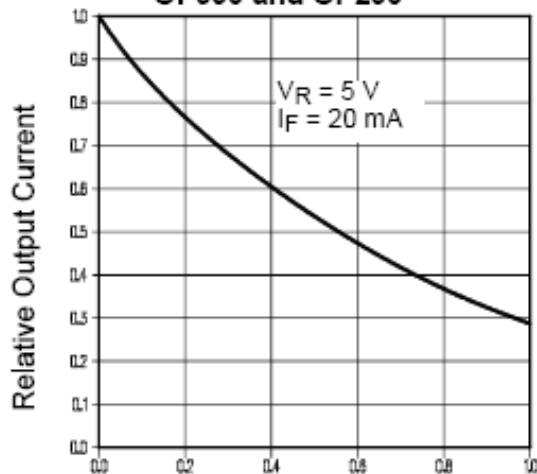
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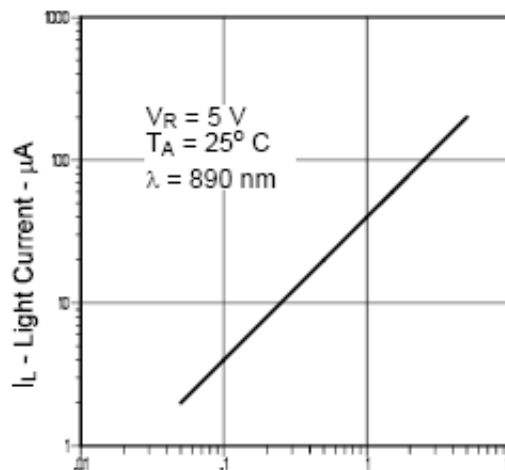
OP999

Coupling Characteristics OP999 and OP299



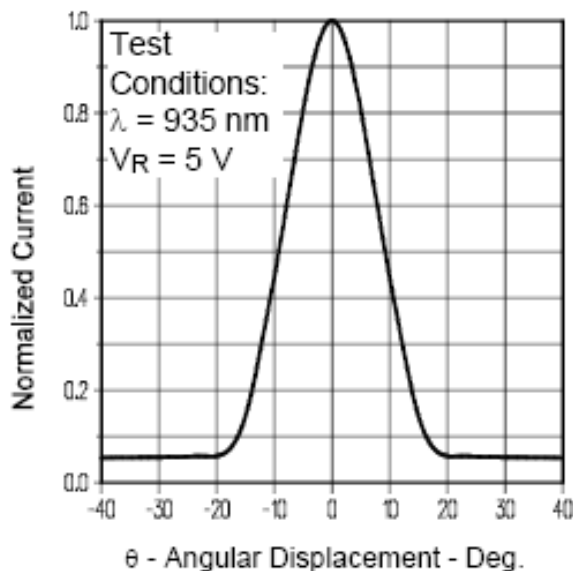
Distance Between Lens Tips - inches

Light Current vs. Irradiance



E_e - Irradiance - mW/cm^2

Light Current vs. Angular Displacement



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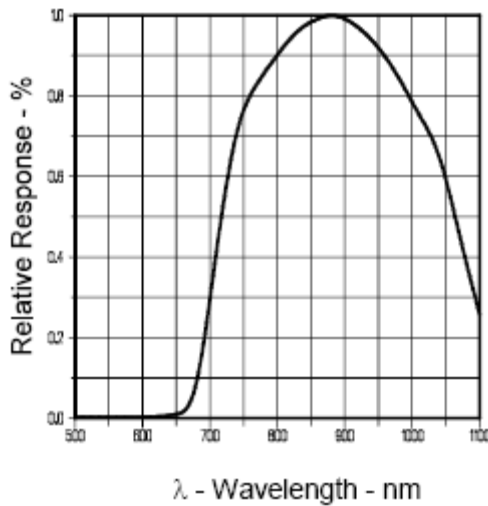
TT Electronics | OPTEK Technology
2900 E. Plano Pkwy, Plano, TX 75074 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

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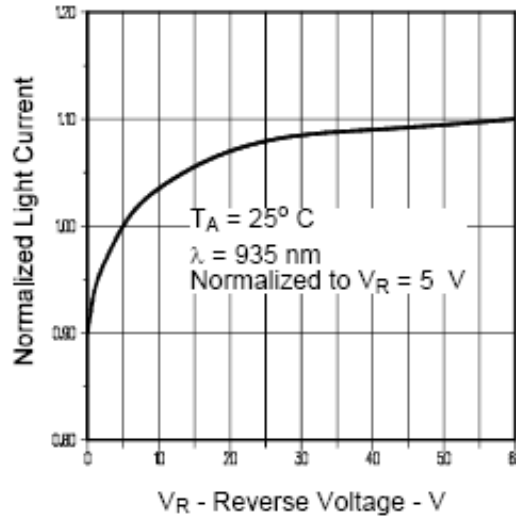
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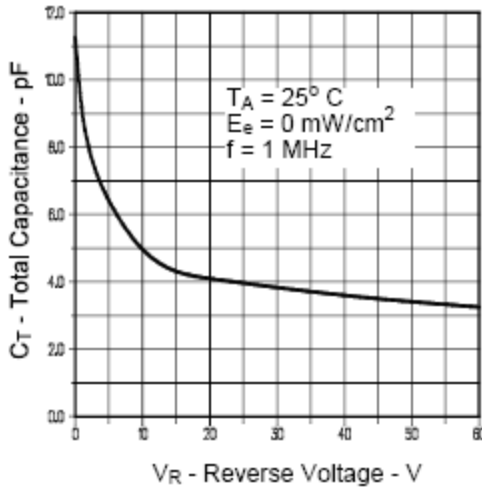
Relative Response vs. Wavelength



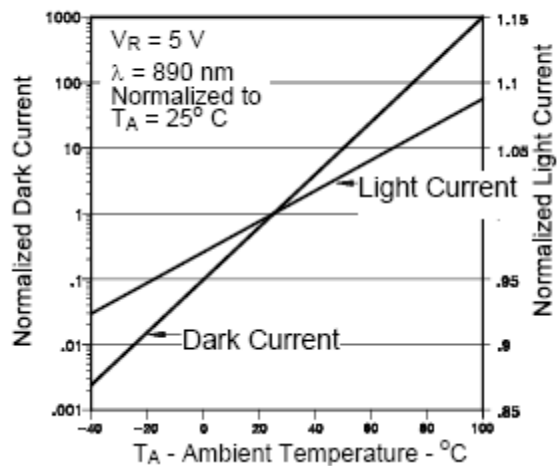
Normalized Light Current vs Reverse Voltage



Total Capacitance vs Reverse Voltage



Normalized Light and Dark Current vs Ambient Temperature



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TT Electronics | OPTeK Technology
 2900 E. Plano Pkwy, Plano, TX 75074 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com